

April 2010 SPM TM

FPAB30BH60B

Smart Power Module(SPM $^{\otimes}$) for Front-End Rectifier

General Description

FPAB30BH60B is an advanced smart power module(SPM®) of PFC(Power Factor Correction) that Fairchild has newly developed and designed mainly targeting mid-power application especially for an air conditioners. It combines optimized circuit protection and drive IC matched to high frequency switching IGBT. System reliability is futher enhanced by the integrated under-voltage lock-out and over-current protection function.

Features

- Low thermal resistance due to $\,\mathrm{Al_2O_3}\text{-DBC}$ substrate
- 600V-30A Single phase IGBT PWM converter including a drive IC for gate driving and protection
- · Typical switching frequency of 20kHz
- Isolation rating of 2500Vrms/min.

Applications

· Home appliances application like air conditioner

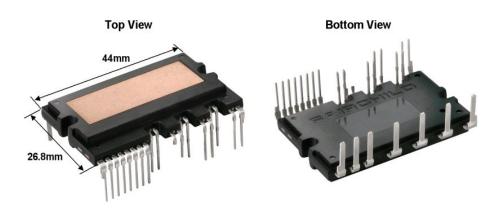


Fig. 1.

Integrated Power Functions

• PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

Integrated Drive, Protection and System Control Functions

- For IGBT: Gate drive circuit, Overcurrent circuit protection (OC), Control supply circuit under-voltage (UV) protection
- · Fault signaling: Corresponding to a UV fault and OC fault
- Input interface: 3.3/5V CMOS/LSTTL compatible, Schmitt trigger input

Pin Configuration

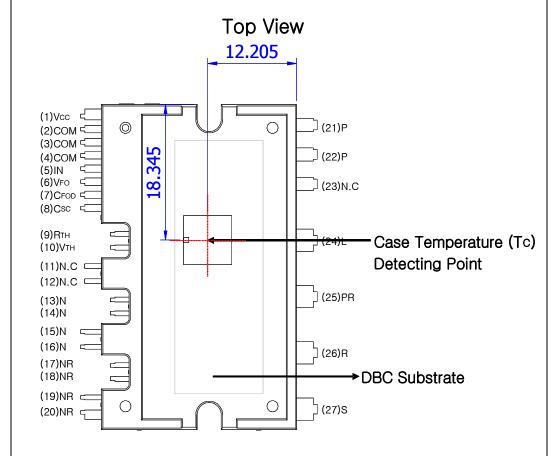


Fig. 2.

 $\textbf{Note}: \ \ \text{For the measurement point of case temperature} (T_C), \ please \ refer \ to \ Fig. \ 2.$

Pin Descriptions

Pin Number	Pin Name	Pin Description
1	V_{CC}	Common Bias Voltage for IC and IGBT Driving
2,3,4	COM	Common Supply Ground
5	IN	Signal Input for IGBT
6	V_{FO}	Fault Output
7	C_{FOD}	Capacitor for Fault Output Duration Time Selection
8	c_{sc}	Capacitor (Low-pass Filter) for Over Current Detection
9	R _(TH)	NTC Thermistor terminal
10	$V_{(TH)}$	NTC Thermistor terminal
11,12	N.C	No Connection*
13~16	N	IGBT emitter
17~20	N_R	Negative DC-Link of Rectifier
21,22	21,22 P Positive Rail of DC–Link	
23	N.C	No Connection
24	L	Reactor connection pin
25	P _R	Positive DC-Link of Rectifier
26	R	AC input for R-phase
27	S	AC input for S-phase

^{* 11}th and 12th pins are cut. Please refer to package outline drawings for more detail.

Internal Equivalent Circuit and Input/Output Pins

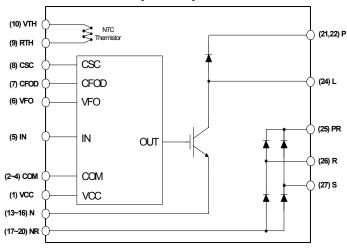


Fig. 3.

Package Marking & Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FPAB30BH60B	FPAB30BH60B	SPM27-IC	-	-	10

Absolute Maximum Ratings ($T_J = 25$ °C, Unless Otherwise Specified) **Converter Part**

Item	Symbol	Condition	Rating	Unit
Supply Voltage	V _i	Applied between R-S	264	V_{RMS}
Supply Voltage (Surge)	V _{i(Surge)}	Applied between R-S	500	V
Output Voltage	V _{PN}	Applied between P- N	450	V
Output Voltage (Surge)	V _{PN(Surge)}	Applied between P- N	500	V
Collector-emitter Voltage	V _{CES}		600	V
Each IGBT Collector Current	I _C	T _C = 25°C, T _J < 150°C	30	Α
Each IGBT Collector Current (peak)	I _{CP}	T _C = 25°C, T _J < 150°C Under 1ms pulse width	60	Α
Collector Dissipation	P _C	T _C = 25°C per One IGBT	104	W
Repititive Peak Reverse Voltage	V_{RRM}		600	V
Peak Forward Surge Current	I _{FSM}	Single half sine-wave	350	Α
Operating Junction Temperature	TJ		-40 ~ 150	°C

Control Part

Item	Symbol	Condition	Rating	Unit
Control Supply Voltage	V_{CC}	Applied between V _{CC} - COM	20	V
Input Signal Voltage	V _{IN}	Applied between IN - COM	-0.3~V _{CC} +0.3	V
Fault Output Supply Voltage	V_{FO}	Applied between V _{FO} - COM	-0.3~V _{CC} +0.3	V
Fault Output Current	I _{FO}	Sink Current at V _{FO} Pin	5	mA
Current Sensing Input Voltage	V_{SC}	Applied between C _{SC} - COM	-0.3~V _{CC} +0.3	V

Total System

Item	Symbol	Condition	Rating	Unit
Storage Temperature	T _{STG}		-40 ~ 125	°C
Isolation Voltage	100	60Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V _{rms}

Thermal Resistance

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal	$R_{\theta(j-c)Q}$	IGBT	-	-	1.2	°C/W
Resistance	$R_{\theta(j-c)F}$	FRD	-	-	1.4	°C/W
	$R_{\theta(j-c)R}$	Rectifier	-	-	1.7	°C/W

Electrical Characteristics (T_J = 25°C, Unless Otherwise Specified)

Converter Part

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
IGBT saturation voltage	V _{CE(sat)}	V_{CC} =15V, V_{IN} = 5V; I_{C} =30A	-	2.2	2.8	V
FRD forward voltage	V_{FF}	I _F = 30A	-	1.9	2.6	V
Rectifier forward voltage	V_{FR}	I _F = 30A	-	1.2	1.5	V
Switching Times	t _{ON}	V _{PN} = 400V, V _{CC} = 15V, I _C =30A	-	500	-	ns
	t _{C(ON)}	$V_{IN} = 0V \leftrightarrow 5V$, Inductive Load	-	200	-	ns
	t _{OFF}	(Note 1)	-	420	-	ns
	t _{C(OFF)}	(11010-1)	-	100	-	ns
	t _{rr}		-	60	-	ns
	I _{rr}		-	7	-	Α
Collector - emitter Leakage Current	I _{CES}	V _{CE} = V _{CES}	-	-	250	μА

Electrical Characteristics

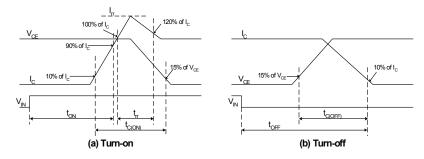


Fig. 4. Switching Time Definition

Control Part

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Quiescent V _{CC} Supply Current	I _{QCCL}	$V_{CC} = 15V$, $IN = 0V$ $V_{CC} - COM$	-	-	26	mA
Fault Output Voltage	V _{FOH}	V_{SC} = 0V, V_{FO} Circuit: 4.7k Ω to 5V Pull-up	4.5	-	-	V
	V _{FOL}	V _{SC} = 1V, V _{FO} Circuit: 4.7kΩ to 5V Pull-up	-	-	0.8	V
Over Current Trip Level	V _{SC(ref)}	V _{CC} = 15V	0.45	0.5	0.55	V
Supply Circuit Under-	UV _{CCD}	Detection Level	10.7	11.9	13.0	V
Voltage Protection	UV _{CCR}	Reset Level	11.2	12.4	13.2	٧
Fault-out Pulse Width	t _{FOD}	C _{FOD} = 33nF (Note 2)	1.4	1.8	2.0	ms
ON Threshold Voltage	V _{IN(ON)}	Applied between IN - COM	2.8	-	-	V
OFF Threshold Voltage	V _{IN(OFF)}		-	-	0.8	V
Resistance of Thermistor	R _{TH}	@ T _{TH} = 25°C (Note3, Fig. 9)	-	47.0	-	kΩ
		@ T _{TH} = 100°C (Note3, Fig. 9)	-	2.9	-	kΩ

Note 2. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation: $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD}[F]$ 3. TTH is the temperature of know case temperature(Tc), please make the experiment considering your application.

^{1.} t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. $t_{C(ON)}$ and $t_{C(OFF)}$ are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

Recommended Operating Condition

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Input Supply Voltage	V _i	Applied between R-S	187	220	253	V
Output Voltage	V_{PN}	Applied between P-N		380	400	V
Control Supply Voltage	V _{CC}	Applied between V _{CC(L)} - COM	13.5	15	16.5	V
Control supply variation	dV _{CC} /dt	, ,	-1	-	1	V/μs
PWM Input Frequency	f _{PWM}	T _J ≤ 150°C per IGBT		20		kHz
Allowable Input Current (Peak)	l _i	T_C < 90°C, V_i =220V, V_{PN} =380V V_{PWM} =20KHz			30	Α

Mechanical Characteristics and Ratings

Item	C	ondition		Units		
	C	Min.	Тур.	Max.	Ullits	
Mounting Torque	Mounting Screw: - M3	Recommended 0.62N•m	0.51	0.62	0.72	N•m
Device Flatness	Note Fig. 5		0	-	+120	μm
Weight			-	15.00	-	g

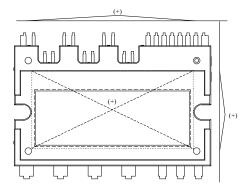
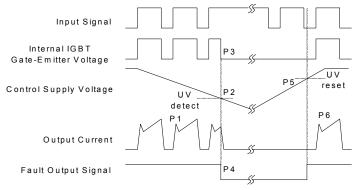


Fig. 5. Flatness Measurement Position

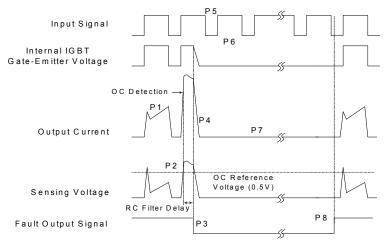




- P1: Normal operation IGBT ON and conducting current
- P2: Under voltage detection
- P3 : IGBT gate interrupt
- P4 : Fault signal generation
- P5 : Under voltage reset

P6: Normal operation - IGBT ON and conducting current

Fig. 6. Under-Voltage Protection



- P1 : Normal operation IGBT ON and conducting current
- P2 : Over current detection
- P3: IGBT gate interrupt / Fault signal generation
- P4: IGBT is slowly turned off
- P5 : IGBT OFF signal
- P6: IGBT ON signal but IGBT cannot be turned on during the fault Output activation
- P7: IGBT OFF state
- P8: Fault Output reset and normal operation start

Fig. 7. Over Current Protection

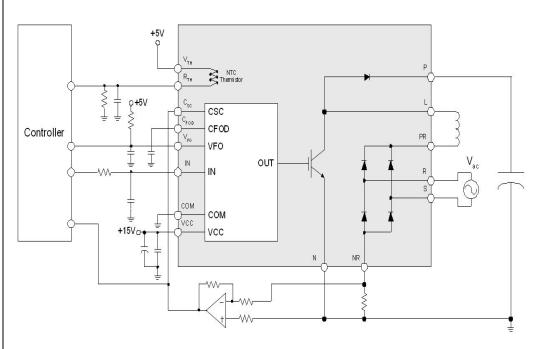
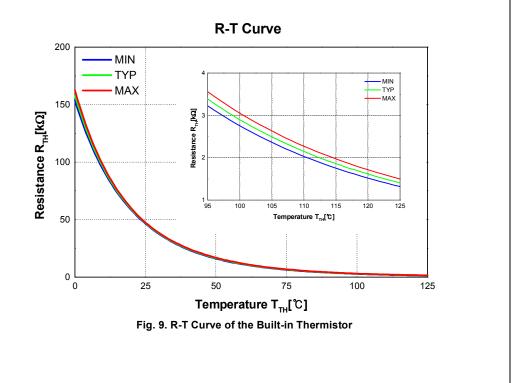
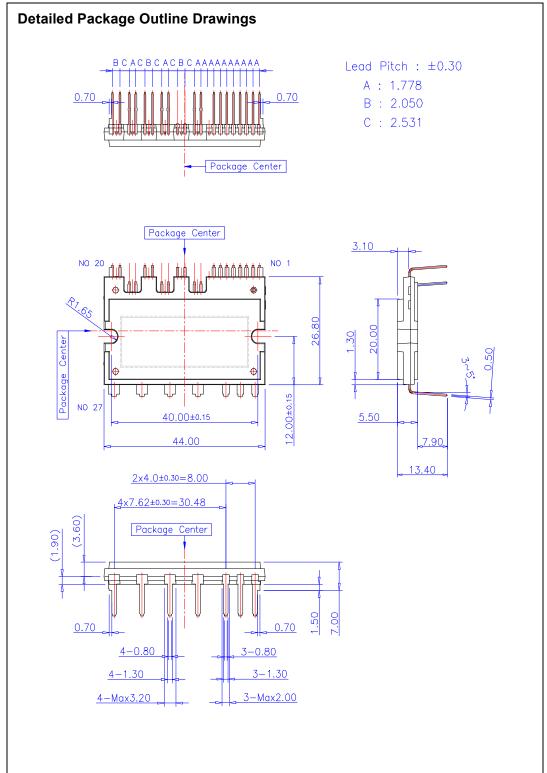
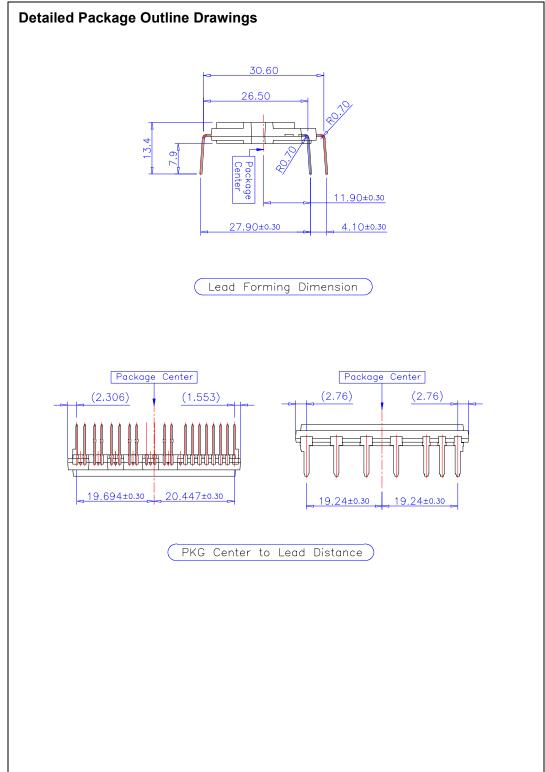
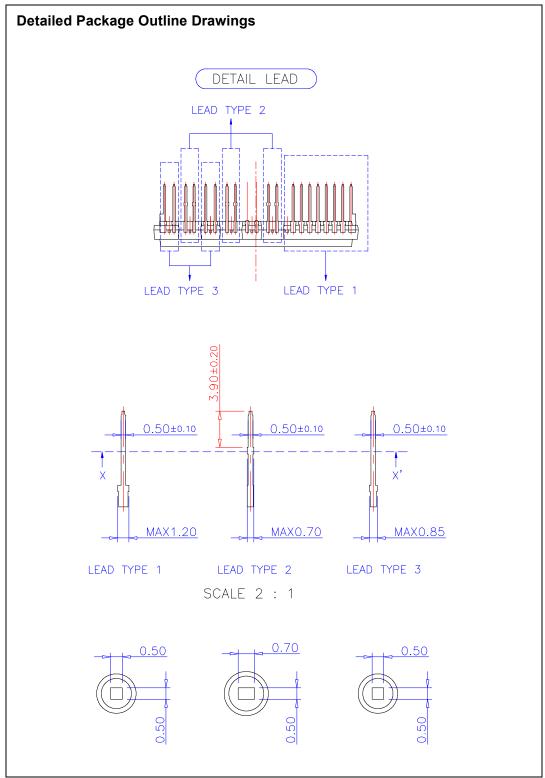


Fig. 8. Application Example













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